RN1961FE(TE85L,F)

RN1961FE(TE85L,F) Information

For Reference Only

Part Number	RN1961FE(TE85L,F)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Description	TRANS 2NPN PREBIAS 0.1W ES6
Package	SOT-563, SOT-666

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

RN1961FE(TE85L,F) Specifications

Manufacturer Part Number	RN1961FE(TE85L,F)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Package	SOT-563, SOT-666
Series	-
Transistor Type	2 NPN - Pre-Biased (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	4.7k
Resistor - Emitter Base (R2) (Ohms)	4.7k
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	250MHz
Power - Max	100mW
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	ES6
	Report errors?

RN1961FE(TE85L,F) Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1961FE(TE85L,F) Payment Methods

RN1961FE(TE85L,F) Shipping Methods

If you have any question about RN1961FE(TE85L,F), please do not hesitate to contact us!
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